

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

Complete if Known

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First Named Inventor	
Art Unit	2811
Examiner Name	H. Vu
Attorney Docket Number	082666-000100US

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U.S. PATENT DOCUMENTS+					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number Kind Code ² (if known)			
	AA	US-5,614,727	03-25-1997	Mauri et al.	
	AB	US-Re: 35,665	11-18-1997	Lin et al.	
	AC	US-5,760,423	06-02-1998	Kamakura et al.	

FOREIGN PATENT DOCUMENTS								
Examiner Initials ^a	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ²
		Country Code ³	Number ⁴	Kind Code ⁵ (if known)				
	AD	JP	10-233382	A	09-02-1998			<input checked="" type="checkbox"/>
	AE	JP	10-233529	A	09-02-1998			<input checked="" type="checkbox"/>
	AF	JP	10-270758	A	10-09-1998			<input checked="" type="checkbox"/>

NON-PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	AG	BIRKS, N. et al.; "Introduction to High Temperature Oxidation of Metals"; 1983, Edward Arnold, pp. 66-90.	
	AH	JARZEBSKI, Z.M.; "Oxide semiconductors", 1973, Pergamon Press, pp. 150-189.	

Date
Considered

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.